Switching Diode

Features

• Pb-Free Package is Available



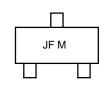
ON Semiconductor®

http://onsemi.com









MARKING DIAGRAM

JF Specific Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
BAL99LT1	SOT-23	3000 / Tape & Reel
BAL99LT1G	SOT–23 (Pb–Free)	3000 / Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	70	Vdc
Peak Forward Current	١ _F	100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1), $T_A = 25^{\circ}C$	P _D	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$	PD	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance,			
Junction-to-Ambient	$R_{ hetaJA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

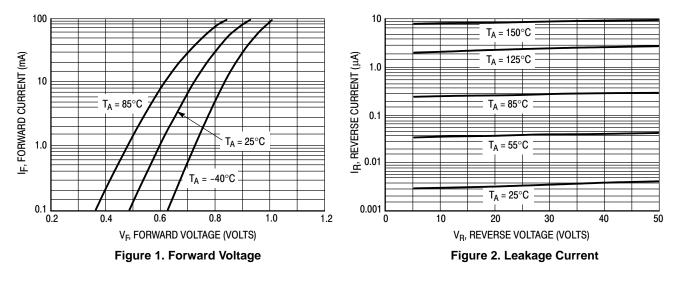
1. FR-5 = 1.0 \times 0.75 \times 0.062 in.

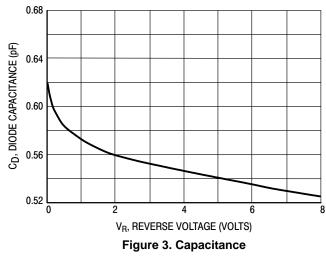
2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current $(V_R = 70 \text{ Vdc})$ $(V_R = 25 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ $(V_R = 70 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I _R		2.5 30 50	μAdc
Reverse Breakdown Voltage, (I _R = 100 μAdc)	V _(BR)	70	-	Vdc
Forward Voltage, $(I_F = 1.0 \text{ mAdc})$ $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 150 \text{ mAdc})$	VF		715 855 1000 1250	mV
Recovery Current, (I _F = 10 mAdc, V _R = 5.0 Vdc, R _L = 500 Ω)	Q _S	-	45	рС
Diode Capacitance, $(V_R = 0, f = 1.0 \text{ MHz})$	CD	-	1.5	pF
Reverse Recovery Time, (I _F = I _R = 10 mAdc, R _L = 100 Ω , measured at I _R = 1.0 mAdc)	t _{rr}	-	6.0	ns
Forward Recovery Voltage, ($I_F = 10 \text{ mAdc}$, $t_r = 20 \text{ ns}$)	V _{FR}	-	1.75	Vdc

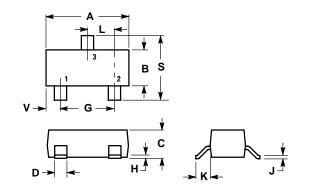
TYPICAL CHARACTERISTICS





PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AH**



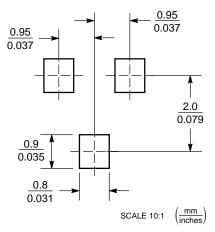
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. 318–03 AND -07 OBSOLETE, NEW STANDARD 318–08.
- STANDARD 318-08.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
κ	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
v	0.0177	0.0236	0.45	0.60	

STYLE 18:

PIN 1. NO CONNECTION 2. CATHODE 3. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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